Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.8)	V_{pp}	4.5	kV

ELECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	V_D =12V R_L =33	- -	MAX.	35	mA
V_{GT}		- -	MAX.	1	V
V_{GD}	V_D =V_{DRM} T_j =150 R_L =3.3K	- -	MIN.	0.2	V
I_L	I_G =1.2I_{GT}	-	MAX.	30	mA
				60	
I_H	I_T =500mA		MAX.	30	mA
dV/dt	V_D=400V Gate Open T_j =150		MIN.	600	V s
(dI/dt)c	G 9 G W F j=9150V 7		MIN.	5	A/ms
t_{on}	I_G=40mA I_A=200mA I_R=20mA T_j=25		TYP.	3	s
t_{off}				60	

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX .)	Unit
V_{TM}	I_{TM} =17A t_p=380 s	T_j=25	1.4	V
V_{TO}	Threshold voltage	T_j=150	0.75	V
R_D	Dynamic resistance	T_j=150	37	P
I_{DRM}	V_D =V_{DRM} V_R =V_{RRM}	T_j=25	5	A
I_{RRM}		T_j=150		

ORDERING INFORMATION

T 12 35 H -

FIG.1 Maximum power dissipation versus RMS on-state current

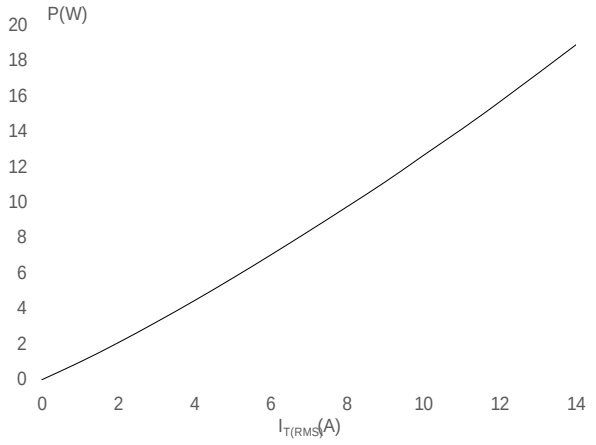
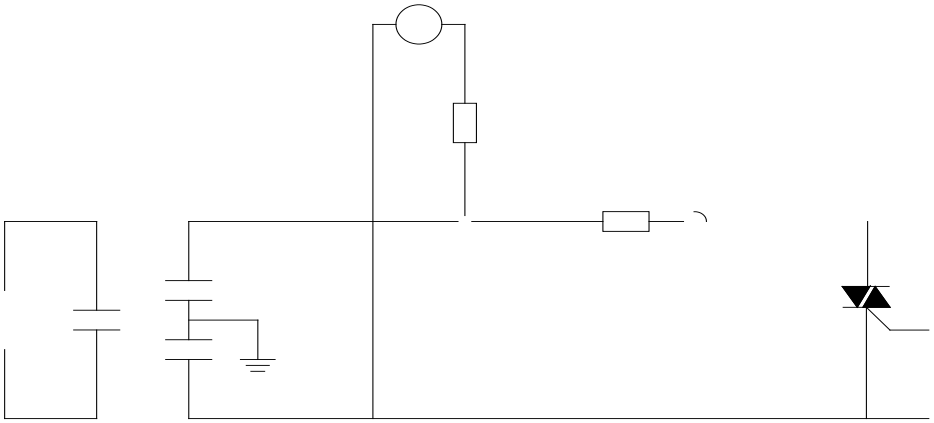


FIG.2: RMS on-state current versus case temperature

FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

FIG.8 ÖTest circuit for inductive and resistive loads to IEC-61000-4-5 standards

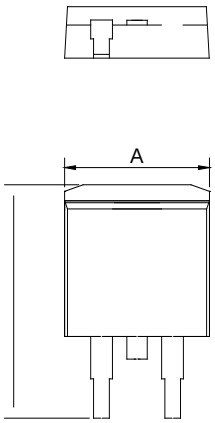


ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
T1235H-6E	600	35	TO-263	50	Tube

T1235H-6E-TR>>BDC 0.001 Tc -

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.40		9.60	0.37		0.378
D	2.40			0.094		
E	1.20		1.50	0.047		0.059
F	0.75		0.85	0.029		0.033
G			1.50			
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0		0.25			
M	1.25		1.35			

DELIVERY MODE

